# **BAT54VV**

# Schottky barrier triple diode in ultra small SOT666 package

Rev. 02 — 15 January 2010

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

Planar Schottky barrier triple diode with an integrated guard ring for stress protection. Three electrically isolated Schottky barrier diodes, encapsulated in a SOT666 ultra small SMD plastic package.

#### 1.2 Features

- Low forward voltage
- Ultra small SMD plastic package
- Low capacitance
- Flat leads: excellent coplanarity and improved thermal behavior

#### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Inverse-polarity protection

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_R$	continuous reverse voltage		-	-	30	V
I <sub>F</sub>	continuous forward current		-	-	200	mA

# 2. Pinning information

Table 2. Pinning

Table 2.	rinning		
Pin	Description	Simplified outline	Symbol
1	anode (diode 1)		
2	anode (diode 2)	6    5    4	6 5 4
3	anode (diode 3)		
4	cathode (diode 3)		1 2 3
5	cathode (diode 2)	0	sym046
6	cathode (diode 1)	123 SOT666	





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#### Schottky barrier triple diode in ultra small SOT666 package

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAT54VV	-	plastic surface mounted package; 6 leads	SOT666

# 4. Marking

Table 4. Marking codes

Type number	Marking code
BAT54VV	C6

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per diode						
$V_R$	continuous reverse voltage			-	30	V
I <sub>F</sub>	continuous forward current			-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s; } \delta \le 0.5$		-	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	$t_{p} < 10 \text{ ms}$		-	600	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[1][2]	-	170	mW
Tj	junction temperature			-	125	°C
T <sub>amb</sub>	ambient temperature			-65	+125	°C
T <sub>stg</sub>	storage temperature			-65	+150	°C

<sup>[1]</sup> Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

#### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	590	K/W

<sup>[1]</sup> Refer to SOT666 standard mounting conditions.

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<sup>[2]</sup> Single diode loaded.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

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BAT54V

## Schottky barrier triple diode in ultra small SOT666 package

# 7. Characteristics

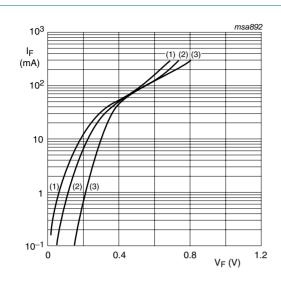
Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

	<u> </u>					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V <sub>F</sub>	forward voltage	see <u>Figure 1</u> ;	<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	-	240	mV
		$I_F = 1 \text{ mA}$	-	-	320	mV
		I <sub>F</sub> = 10 mA	-	-	400	mV
		$I_F = 30 \text{ mA}$	-	-	500	mV
		I <sub>F</sub> = 100 mA	-	-	800	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25 V; see Figure 2	-	-	2	μΑ
C <sub>d</sub>	diode capacitance	$V_R = 1 \text{ V; } f = 1 \text{ MHz;}$ see Figure 3	-	-	10	pF

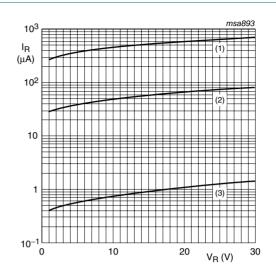
<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 





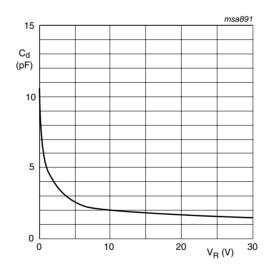
- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values

**Product data sheet** 

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# 8. Package outline

#### Plastic surface-mounted package; 6 leads

**SOT666** 

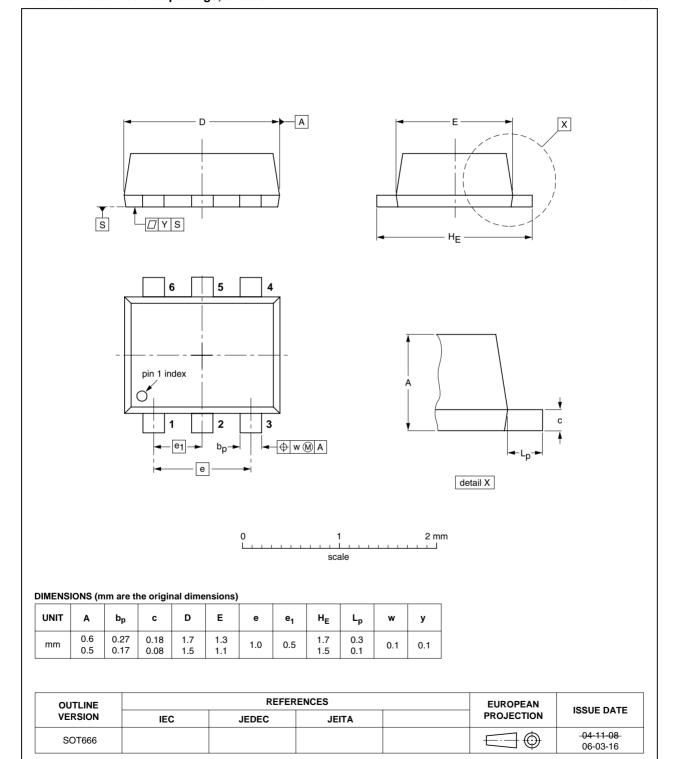


Fig 4. Package outline SOT666.



# 9. Packing information

#### Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			4000
BAT54VV	SOT666	4 mm pitch, 8 mm tape and reel	-115

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.

# 10. Revision history

#### Table 9. **Revision history**

**Product data sheet** 

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAT54VV_2	20100115	Product data sheet	-	BAT54VV_1
Modifications:		eet was changed to reflect w legal definitions and disc		
	<ul> <li>Table 2 "Pinr</li> </ul>	ning": updated		
	<ul> <li>Figure 4 "Pa</li> </ul>	ckage outline SOT666.": up	odated	
BAT54VV_1	20040914	Product data sheet	-	-

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#### Schottky barrier triple diode in ultra small SOT666 package

# 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### Contact Us:

## > Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

#### > Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

## Customer Service :

Email service@ameya360.com

# Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com